NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

Rev. 8 — 5 December 2011

Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			PNP	Package
	NXP	NXP JEITA JEDEC complem		complement	configuration
PDTC143ZE	SOT416	SC-75	-	PDTA143ZE	ultra small
PDTC143ZM	SOT883	SC-101	-	PDTA143ZM	leadless ultra small
PDTC143ZT	SOT23	-	TO-236AB	PDTA143ZT	small
PDTC143ZU	SOT323	SC-70	-	PDTA143ZU	very small

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Parameter	Conditions	Min	Тур	Max	Unit
collector-emitter voltage	open base	-	-	50	V
output current		-	-	100	mA
bias resistor 1 (input)		3.3	4.7	6.1	kΩ
bias resistor ratio		8	10	12	
	collector-emitter voltage output current bias resistor 1 (input)	collector-emitter voltage open base output current bias resistor 1 (input)	collector-emitter voltageopen base-output current-bias resistor 1 (input)3.3	collector-emitter voltageopen base-output currentbias resistor 1 (input)3.34.7	collector-emitter voltageopen base-50output current100bias resistor 1 (input)3.34.76.1



NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

Pinning information 2.

Pin	Description	Simplified outline	Graphic symbol
SOT23; S	OT323; SOT416		
1	input (base)	_	
2	GND (emitter)	3	
3	output (collector)	12	1 R1 R2 sym007
SOT883			
1	input (base)		
2	GND (emitter)	1 3	
3	output (collector)	2 Transparent top view	1 R1 R2 sym007

Ordering information 3.

Type number	Package	Package					
	Name	Description	Version				
PDTC143ZE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTC143ZM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
PDTC143ZT	-	plastic surface-mounted package; 3 leads	SOT23				
PDTC143ZU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

Marking 4.

Table 5. Marking codes	Mandata and a [1]
Type number	Marking code ^[1]
PDTC143ZE	38
PDTC143ZM	E3
PDTC143ZT	*18
PDTC143ZU	*54

[1] * = placeholder for manufacturing site code

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

5. Limiting values

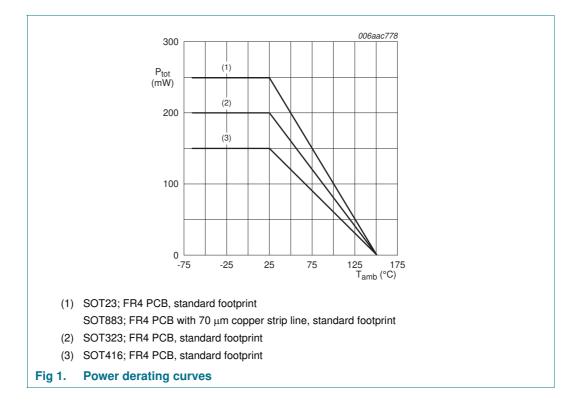
Table 6. In accordai	Limiting values nce with the Absolute Maximum F	Rating System (IEC	60134).		
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
VI	input voltage				
	positive		-	+30	V
	negative		-	-5	V
lo	output current		-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 ms$	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PDTC143ZE (SOT416)		[1][2] _	150	mW
	PDTC143ZM (SOT883)		[2][3]	250	mW
	PDTC143ZT (SOT23)		<u>[1]</u> -	250	mW
	PDTC143ZU (SOT323)		<u>[1]</u> -	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω



6. Thermal characteristics

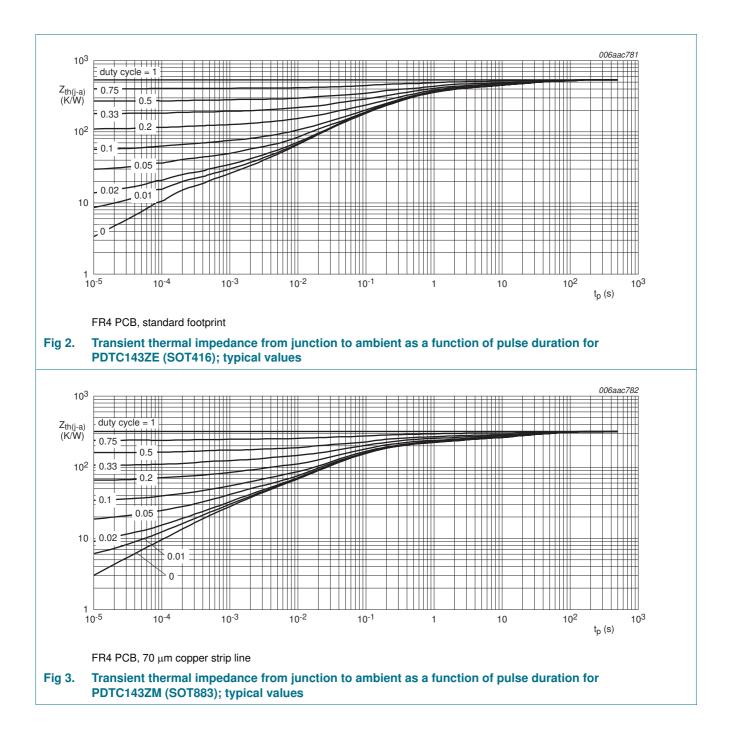
Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	PDTC143ZE (SOT416)		[1][2]	-	830	K/W
	PDTC143ZM (SOT883)		[2][3]	-	500	K/W
	PDTC143ZT (SOT23)		<u>[1]</u> -	-	500	K/W
	PDTC143ZU (SOT323)		<u>[1]</u> -	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

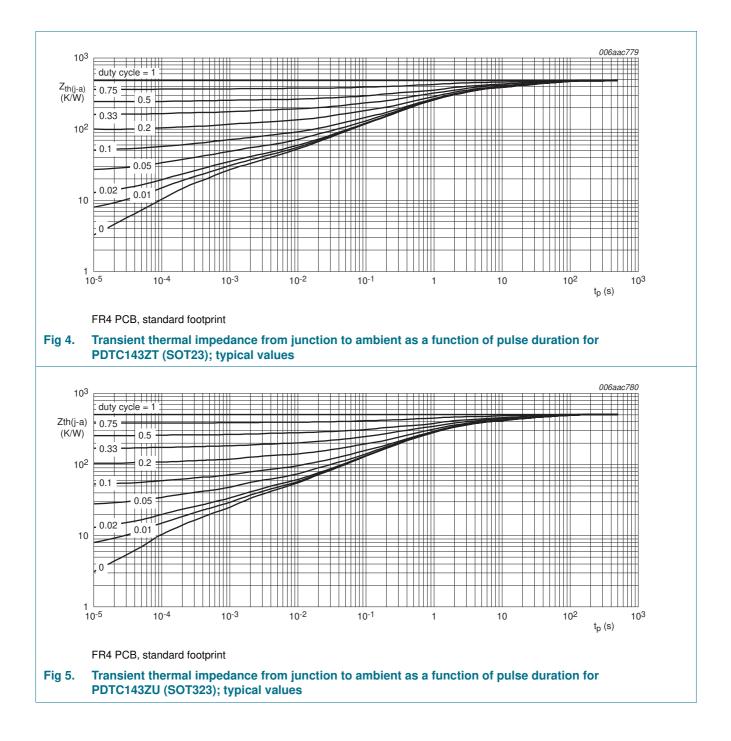
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.

PDTC143Z series



PDTC143Z series



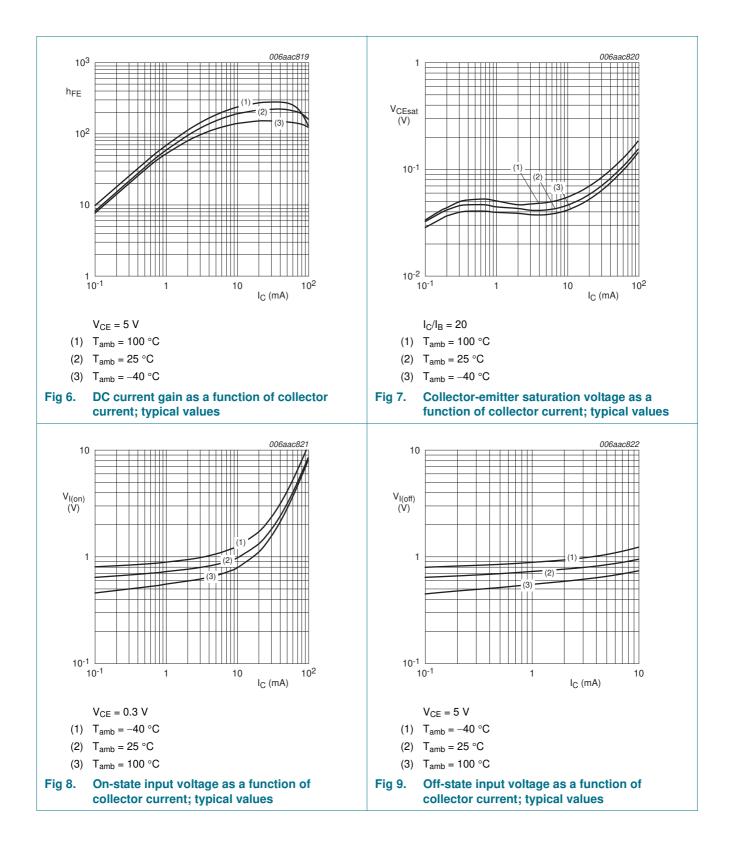
NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
I _{CEO}	collector-emitter	$V_{CE}=30~V;~I_B=0~A$		-	-	1	μA
	cut-off current	$\label{eq:Vce} \begin{array}{l} V_{CE} = 30 \; V; \; I_{B} = 0 \; A; \\ T_{j} = 150 \; ^{\circ}C \end{array}$		-	-	5	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	170	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = 5 \text{ mA}; I_{B} = 0.25 \text{ mA}$		-	-	100	mV
V _{I(off)}	off-state input voltage	$V_{CE}=5~V;~I_{C}=100~\mu A$		-	0.6	0.5	V
V _{I(on)}	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 5 \text{ mA}$		1.3	0.9	-	V
R1	bias resistor 1 (input)			3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio			8	10	12	
C _c	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V}; \text{I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$		-	-	2.5	рF
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz	<u>[1]</u>	-	230	-	MHz

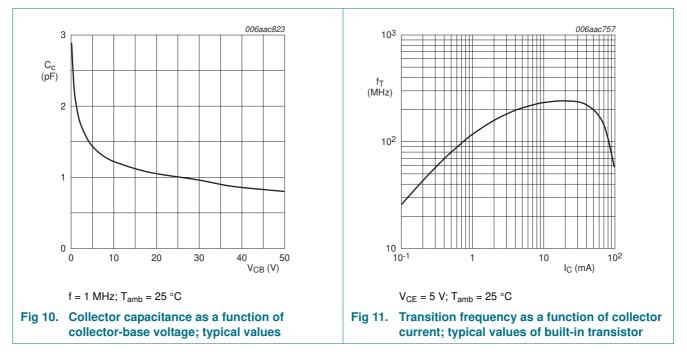
[1] Characteristics of built-in transistor

PDTC143Z series



PDTC143Z series

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω



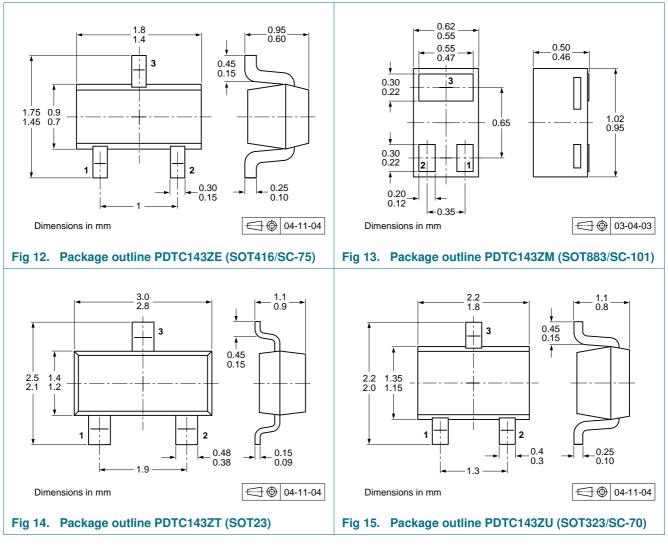
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

9. Package outline



10. Packing information

Table 9.Packing methods

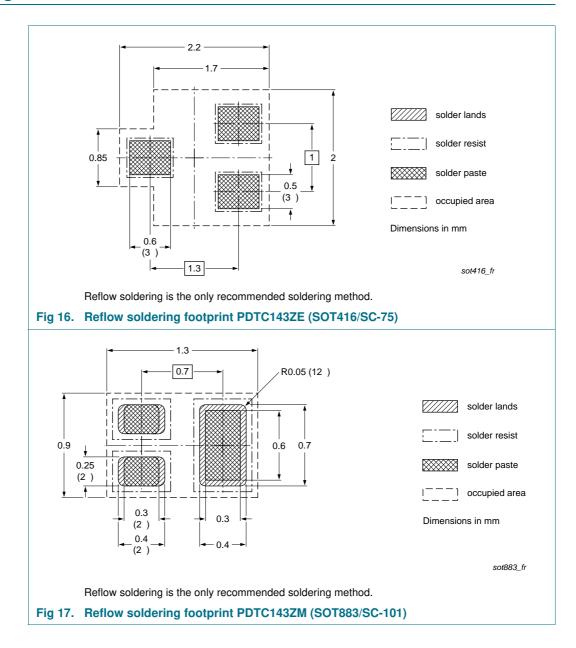
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

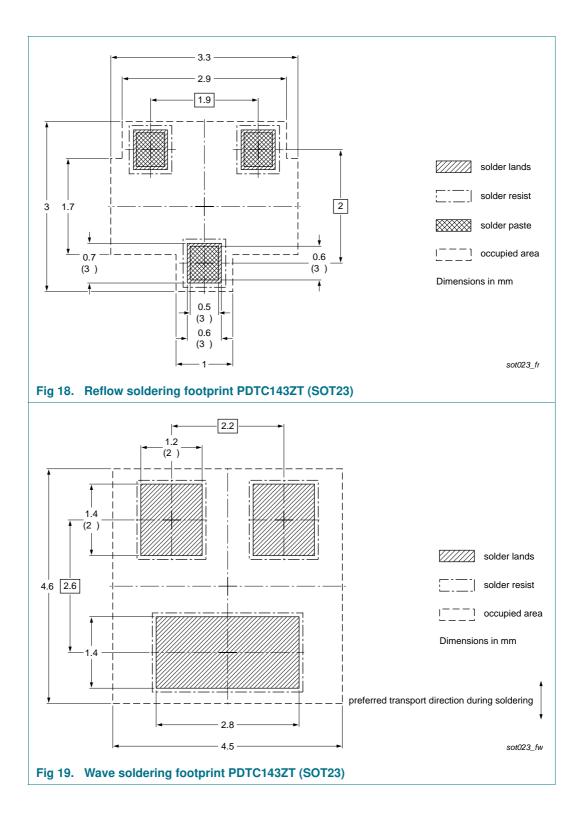
Type number	Package	Description	Packing	Packing quantity		
			3000	5000	10000	
PDTC143ZE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTC143ZM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTC143ZT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTC143ZU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

[1] For further information and the availability of packing methods, see Section 14.

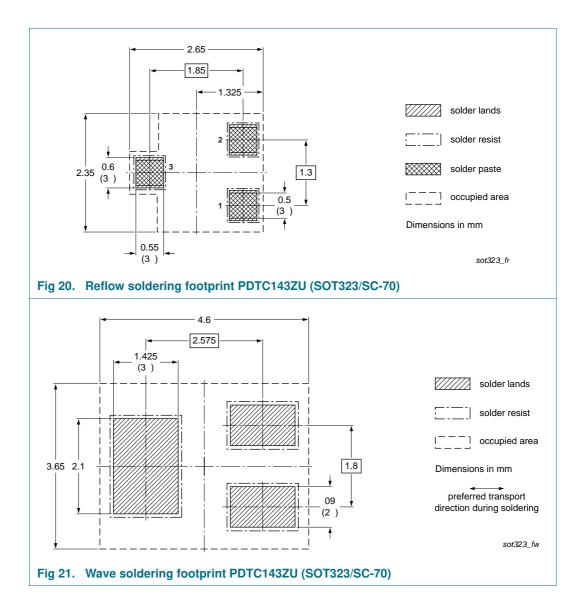
NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

11. Soldering





NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω



NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PDTC143Z_SER v.8	20111205	Product data sheet	-	PDTC143Z_SERIES v.7		
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 					
	 Legal texts have been adapted to the new company name where appropriate. 					
	 Type numbers PDTC143ZEF, PDTC143ZK and PDTC143ZS removed. 					
	<u>Section 1 "Product profile"</u> : updated					
	<u>Section 3 "Ordering information"</u> : added					
	 Section 4 "N 	Marking": updated				
	 Figure 1 to 11: added 					
	<u>Table 6 "Limiting values"</u> : updated					
	 <u>Section 6 "Thermal characteristics"</u>: updated 					
		<u>aracteristics"</u> : V _{i(on)} redefine te input voltage, I _{CEO} update		t voltage, $V_{i(off)}$ redefined to		
	<u>Section 8 "Test information"</u> : added					
	 <u>Section 9 "Package outline"</u>: superseded by minimized package outline drawings 					
	 Section 10 * 	Packing information": addee	Ł			
	 <u>Section 11</u> " 	Soldering": added				
	 Section 13 ' 	Legal information": updated				
PDTC143Z_SERIES v.7	20040816	Product data sheet	-	PDTC143Z_SERIES v.6		
PDTC143Z_SERIES v.6	20040406	Product specification	-	PDTC143Z_SERIES v.5		
PDTC143Z_SERIES v.5	20030910	Product specification	-	PDTC143Z_SERIES v.4		
PDTC143Z SERIES v.4	20030414	Product specification		-		

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PDTC143Z SER

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

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PDTC143Z_SER Product data sheet

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PDTC143Z series

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

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